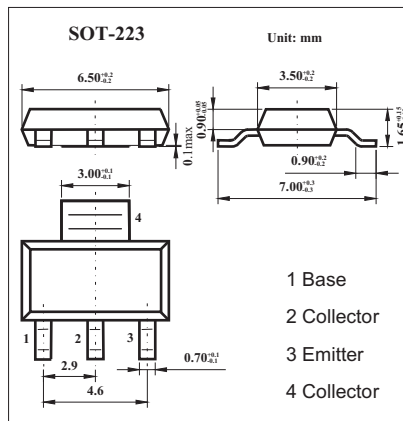


# FZT489

### ■ Features

- Power Dissipation:  $P_c=2W$
- Continuous Collector Current:  $I_c=1A$



### ■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	$V_{CEO}$	30	V
Emitter-base voltage	$V_{EBO}$	5	V
Continuous Collector Current	$I_c$	1	A
power dissipation	$P_c$	2	W
Junction temperature	$T_j$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

### ■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Test conditons	Min	Typ	Max	Unit
Collector to base breakdown voltage	$V_{CBO}$	$I_c=100 \mu A$	50			V
Collector to emitter breakdown voltage	$V_{CEO}$	$I_c=10mA$	30			V
Emitter to base breakdown voltage	$V_{EBO}$	$I_E=100 \mu A$	5			V
Collector cutoff current	$I_{CBO}$	$V_{CB} = 30 V, I_E = 0$			100	nA
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB}=4V, I_c=0$			100	nA
DC current gain	$h_{FE}$	$I_c = 1.0 mA; V_{CE} = 2V$	100			
		$I_c = 1A; V_{CE} = 2V$	100		300	
		$I_c = 2A; V_{CE} = 2V$	60			
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_c = 1A; I_B = 100mA$			0.3	V
		$I_c = 2A; I_B = 200mA$			0.6	V
Output capacitance	$C_{ob}$	$V_{CB} = 10 V, I_E = 0, f=1.0MHz$			10	pF
Transition frequency	$f_T$	$I_c = 50 mA; V_{CE} = 10V; f = 100 MHz$	150			MHz

### ■ Marking

Marking	489
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